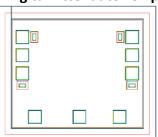
## AMT1613 0 - 20GHz Digital Attenuator Chip



### **Key Features:**

Frequency range: 0 – 20GHz

Insertion loss: 1dBAttenuation: 32dB

Input/output standing wave : 1.2/1.2

Control method : TTLControl method : -5V/1mA

• Chip dimensions: 1.2mm x 1.0mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

### **Description:**

AMT1613 is a one-bit 32dB digital control attenuator, it is designed by Gallium Arsenide (GaAs) process. This chip is designed with ground through metal vias on the back technology, it covers a frequency range of 0  $\sim$  20GHz, typical insertion loss is 1dB, it uses TTL logic control. This chip is for microwave transceiver module, to realize transceiver signal amplitude control function.

## Absolute Maximum Ratings (Ta = 25°C)

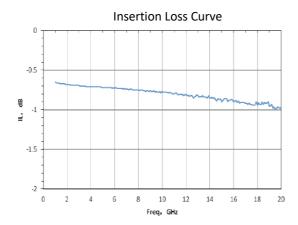
Symbol	Parameter	Value	Remark					
Pin	Input Power	25dBm						
Tch	Operating Temperature	-55 ~ +125°C						
Tm	Sintering Temperature	310°C	30s, N₂ protection					
Tstg	Storage Temperature	-65 ~ +150°C						

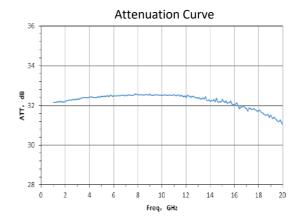
[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

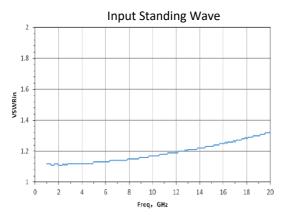
#### **Electrical Characteristics (Ta = 25°C)**

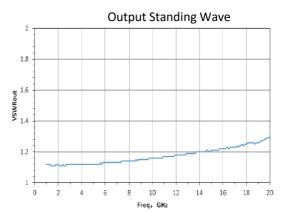
Symbol	Parameter	<b>Test Conditions</b>	Value		Unit	
			Min	Typical	Max	
IL	Insertion Loss		-	1	2	dB
ATT	Attenuation		-	32	•	dB
VSWRin	Input Standing Wave	F: 0 – 20GHz	-	1.2	1.6	ı
VSWRout	Output Standing Wave		-	1.2	1.6	ı

# **Typical Performance**

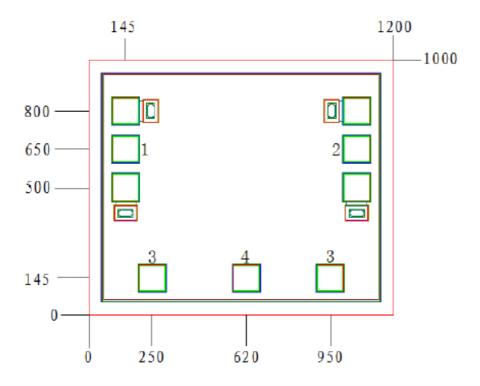




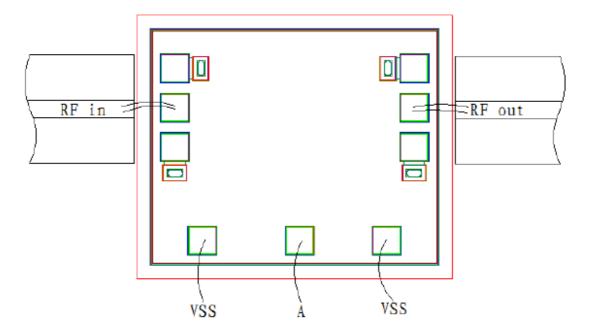




# Chip Dimensions (Unit: $\mu$ m)



## **Chip Layout Diagram**



**Pad Definition** 

Symbol	Function	Dimension	
RFin	RF signal input port, external connect to $50\Omega$ system, no DC blocking capacitor	100μm*100μm	
RFout	RF signal output port, external connect to $50\Omega$ system, no DC blocking capacitor	100μm*100μm	
VSS	-5V power supply	100μm*100μm	
Α	When input high level, attenuator works at attenuating state	100μm*100μm	

Please see Appendix A for details.